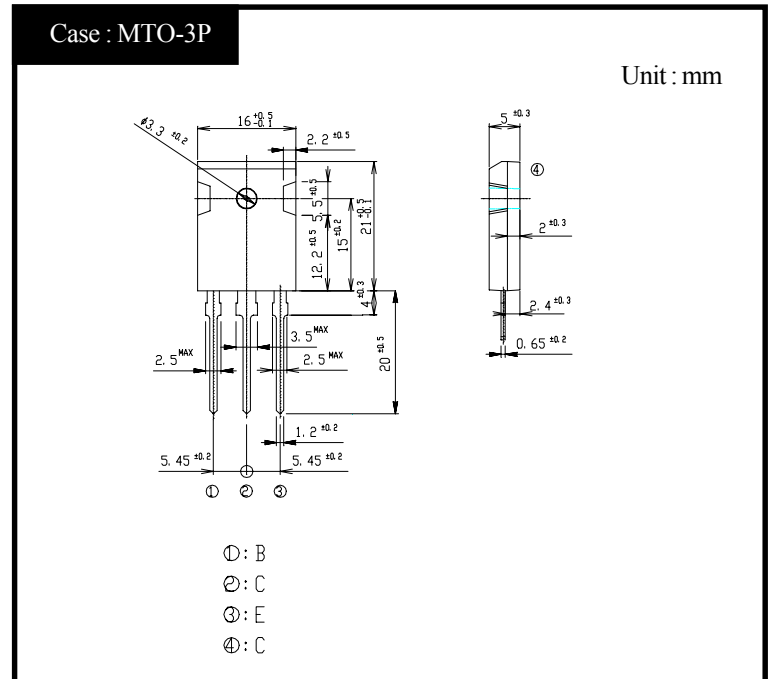


2SC4236
(T6W80HFX)

6A NPN

OUTLINE DIMENSIONS



RATINGS

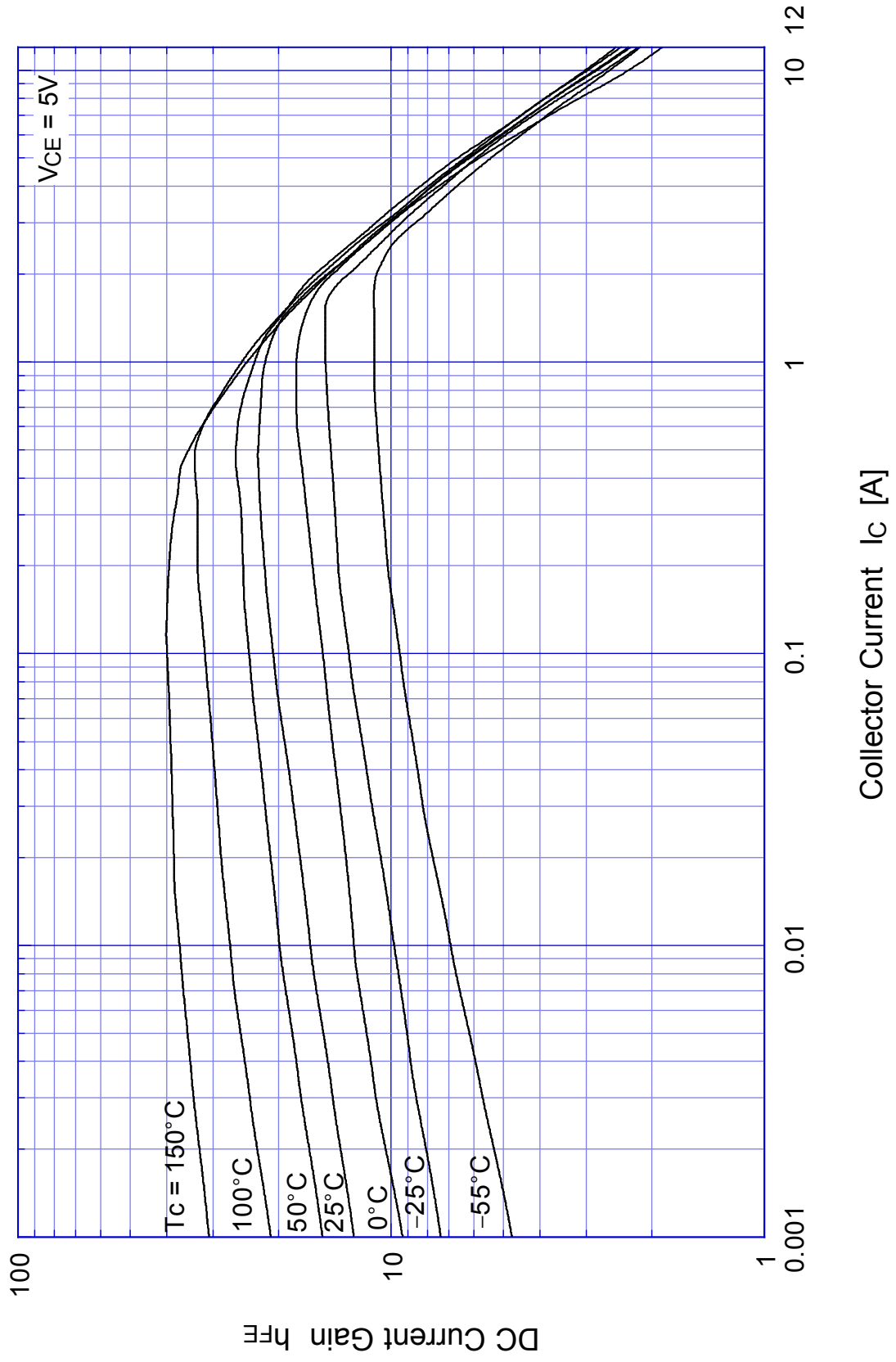
● Absolute Maximum Ratings

Item	Symbol	Conditions	Ratings	Unit
Storage Temperature	T_{stg}		-55~150	°C
Junction Temperature	T_j		150	°C
Collector to Base Voltage	V_{CBO}		1200	V
Collector to Emitter Voltage	V_{CEO}		800	V
Emitter to Base Voltage	V_{EBO}		7	V
Collector Current DC	I_C		6	A
Collector Current Peak	I_{CP}		12	
Base Current DC	I_B		3	A
Base Current Peak	I_{BP}		6	
Total Transistor Dissipation	P_T	$T_c = 25^\circ\text{C}$	100	W
Mounting Torque	TOR	(Recommended torque : 0.5N·m)	0.8	N·m

● Electrical Characteristics ($T_c=25^\circ\text{C}$)

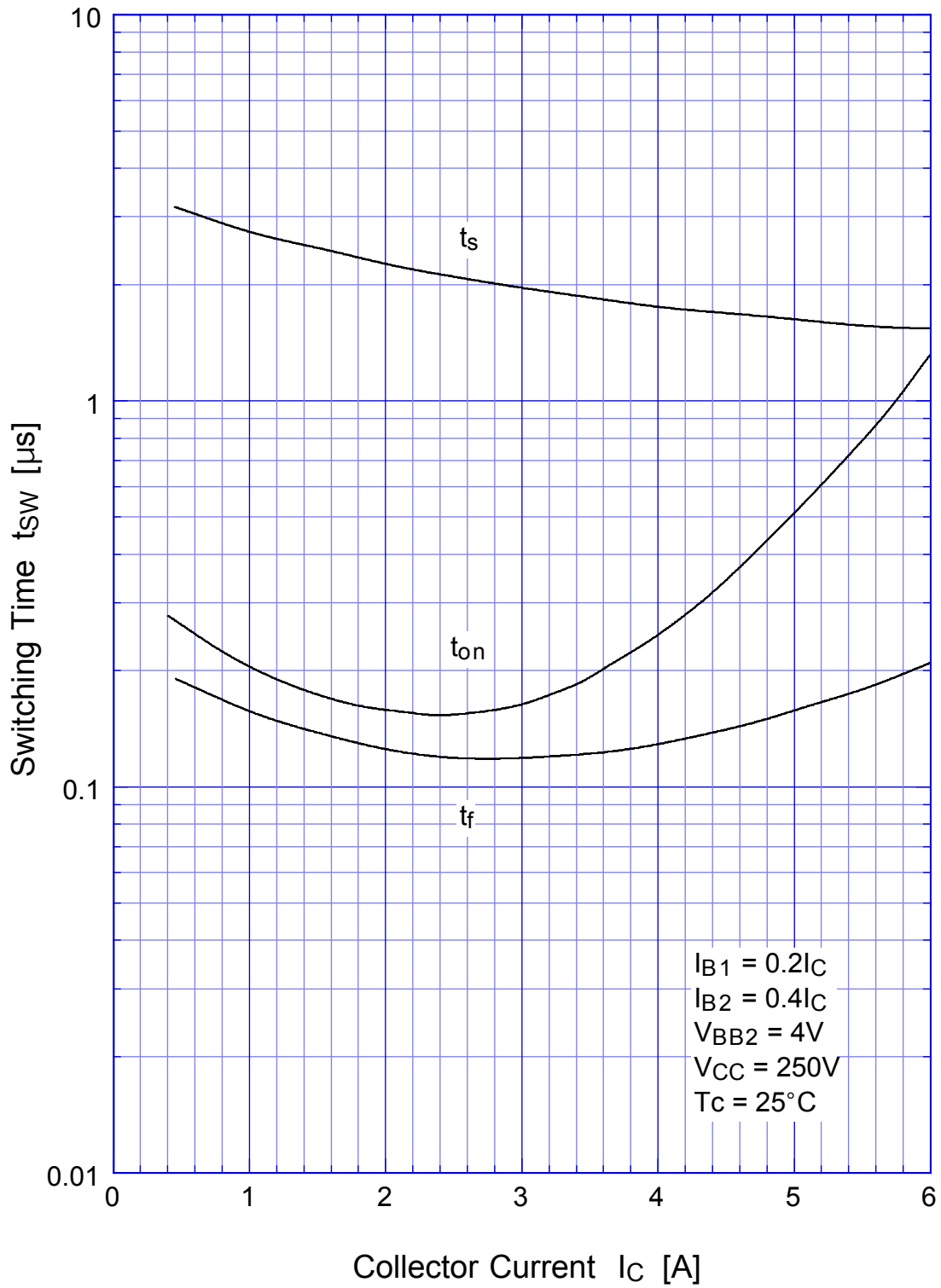
Item	Symbol	Conditions	Ratings	Unit
Collector to Emitter Sustaining Voltage	$V_{CEO(sus)}$	$I_C = 0.2A$	Min 800	V
Collector Cutoff Current	I_{CBO}	At rated Voltage	Max 0.1	mA
	I_{CEO}		Max 0.1	
Emitter Cutoff Current	I_{EBO}	At rated Voltage	Max 0.1	mA
DC Current Gain	h_{FE}	$V_{CE} = 5V, I_C = 3A$	Min 8	
	h_{FEL}	$V_{CE} = 5V, I_C = 1mA$	Min 7	
Collector to Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = 3A$	Max 1.0	V
Base to Emitter Saturation Voltage	$V_{BE(sat)}$	$I_B = 0.6A$	Max 1.5	V
Thermal Resistance	θ_{jc}	Junction to case	Max 1.25	°C/W
Transition Frequency	f_T	$V_{CE} = 10V, I_C = 0.6A$	TYP 8	MHz
Turn on Time	t_{on}	$I_C = 3A$	Max 0.5	μs
Storage Time	t_s	$I_{B1} = 0.6A, I_{B2} = 1.2A$	Max 3.5	
Fall Time	t_f	$R_L = 85 \Omega, V_{BB2} = 4V$	Max 0.3	

2SC4236 $h_{FE} - I_C$

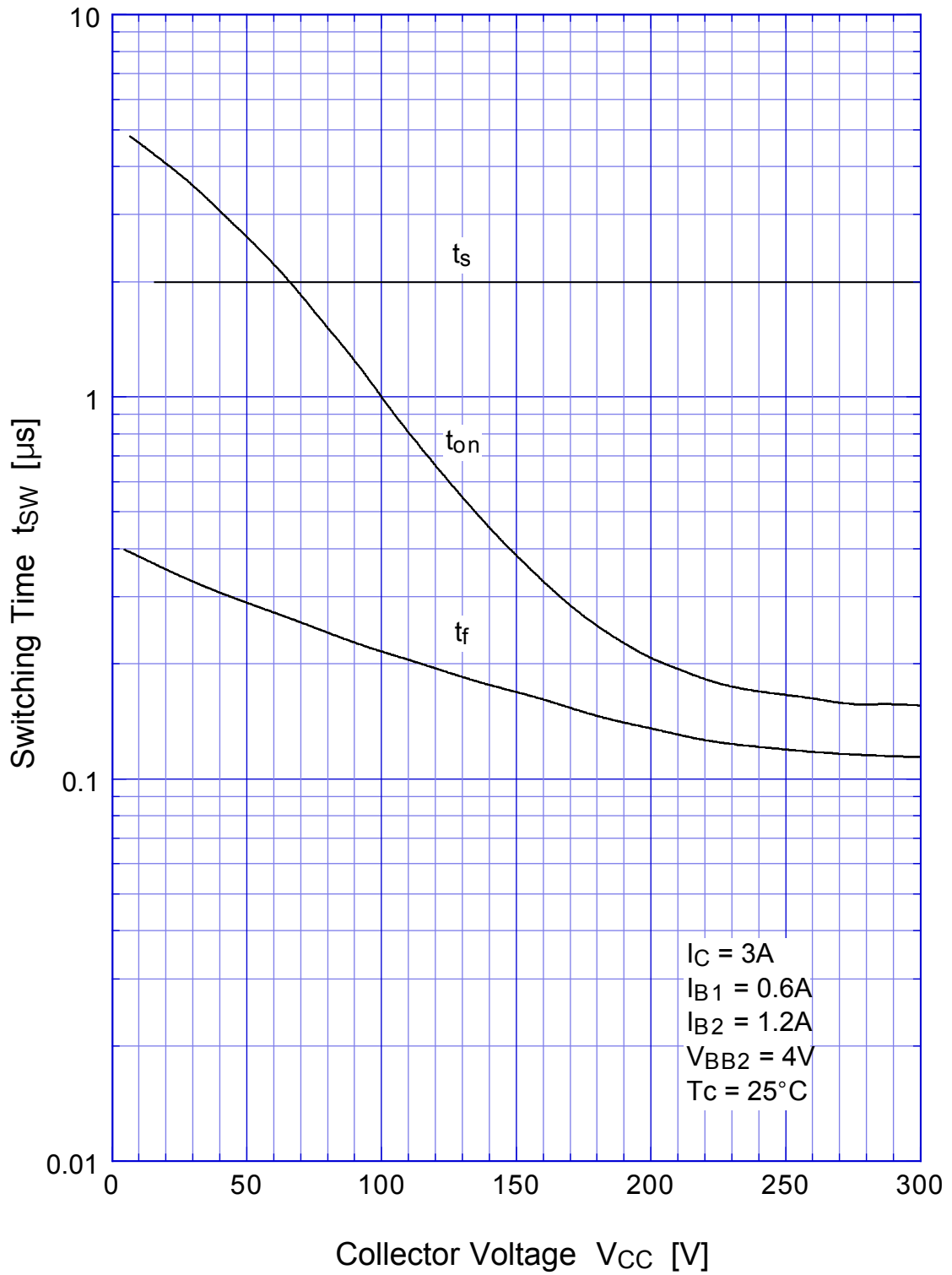


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Switching Time - I_C

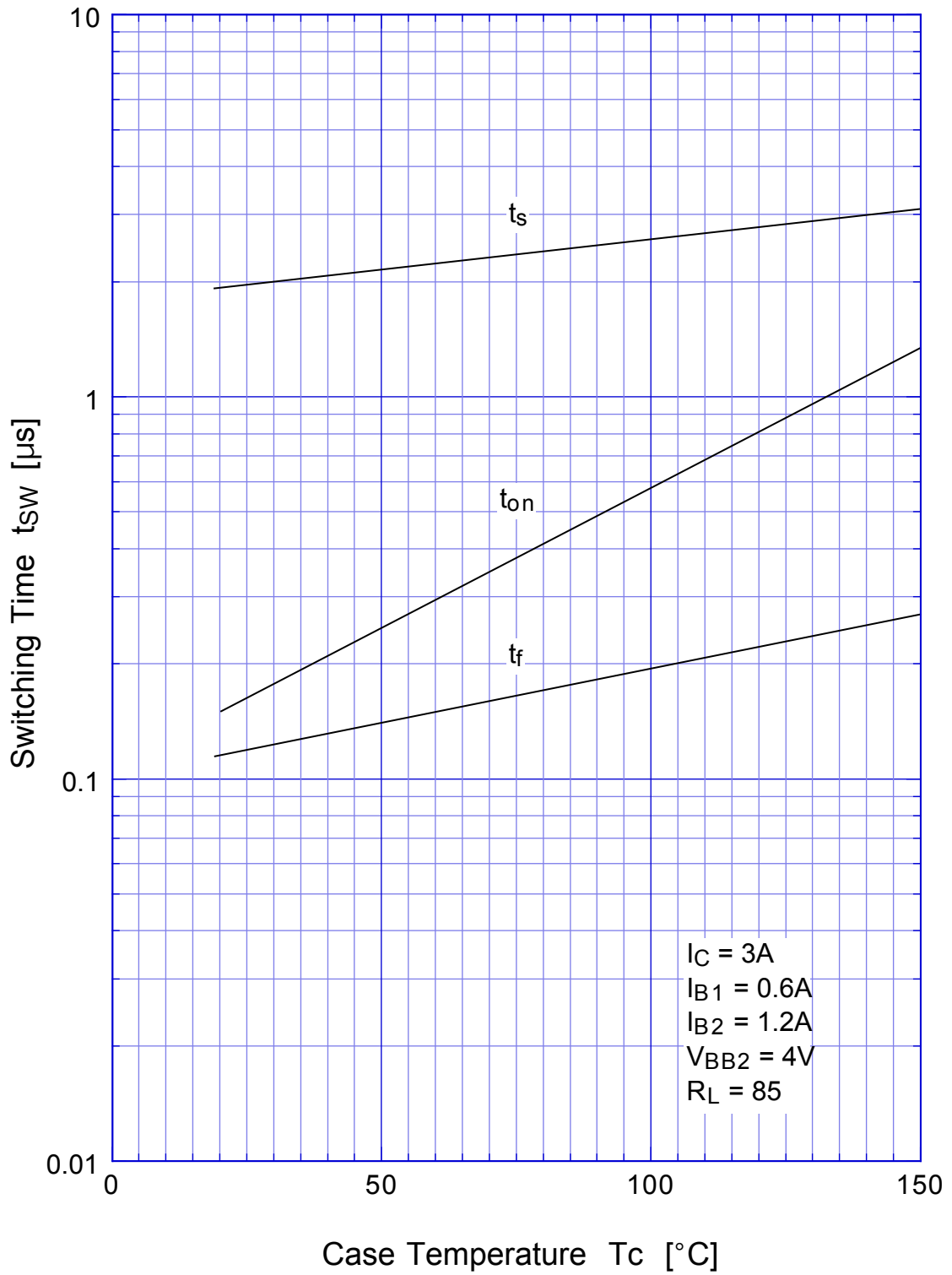


2SC4236 Switching Time - V_{CC}

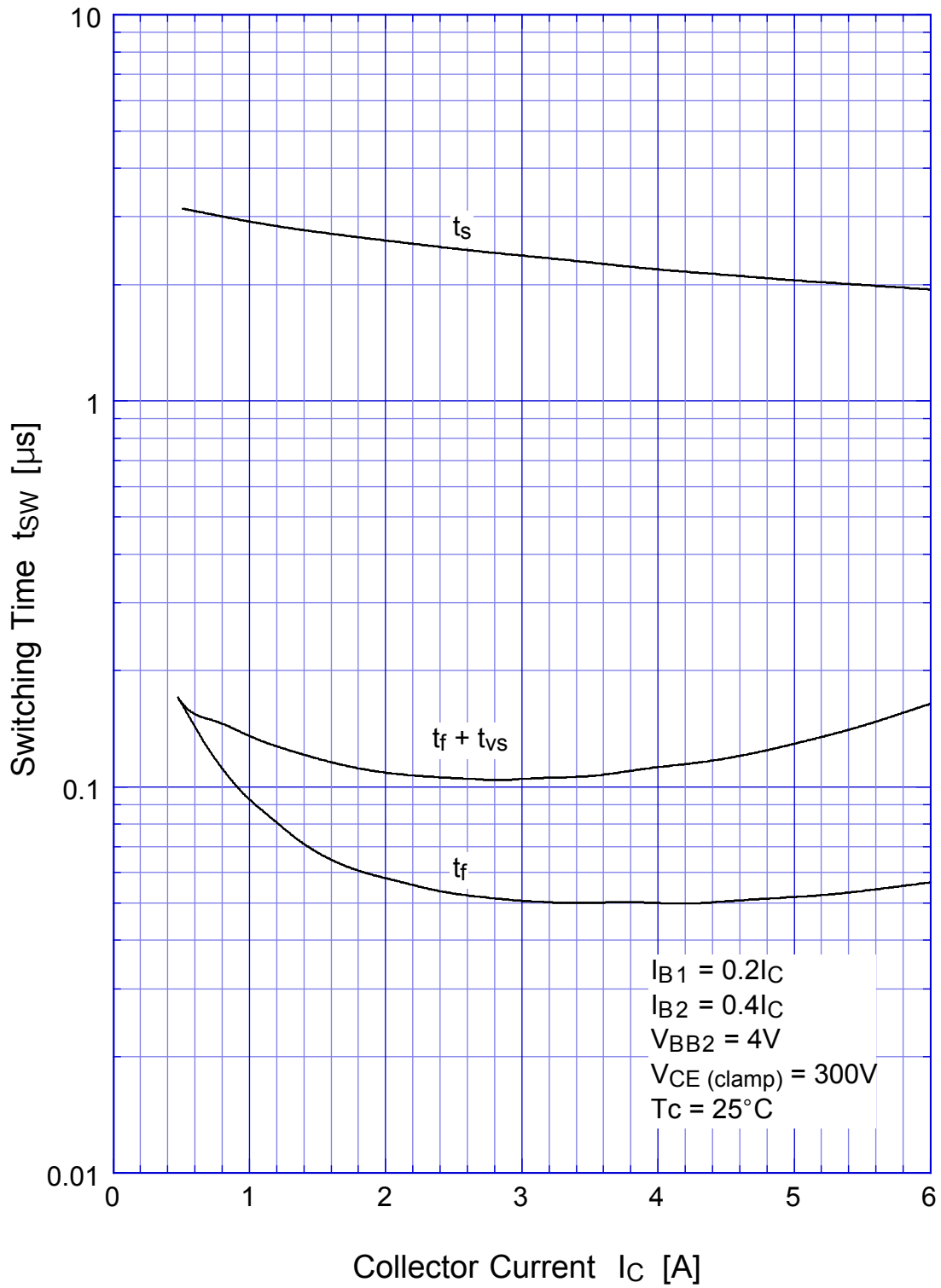


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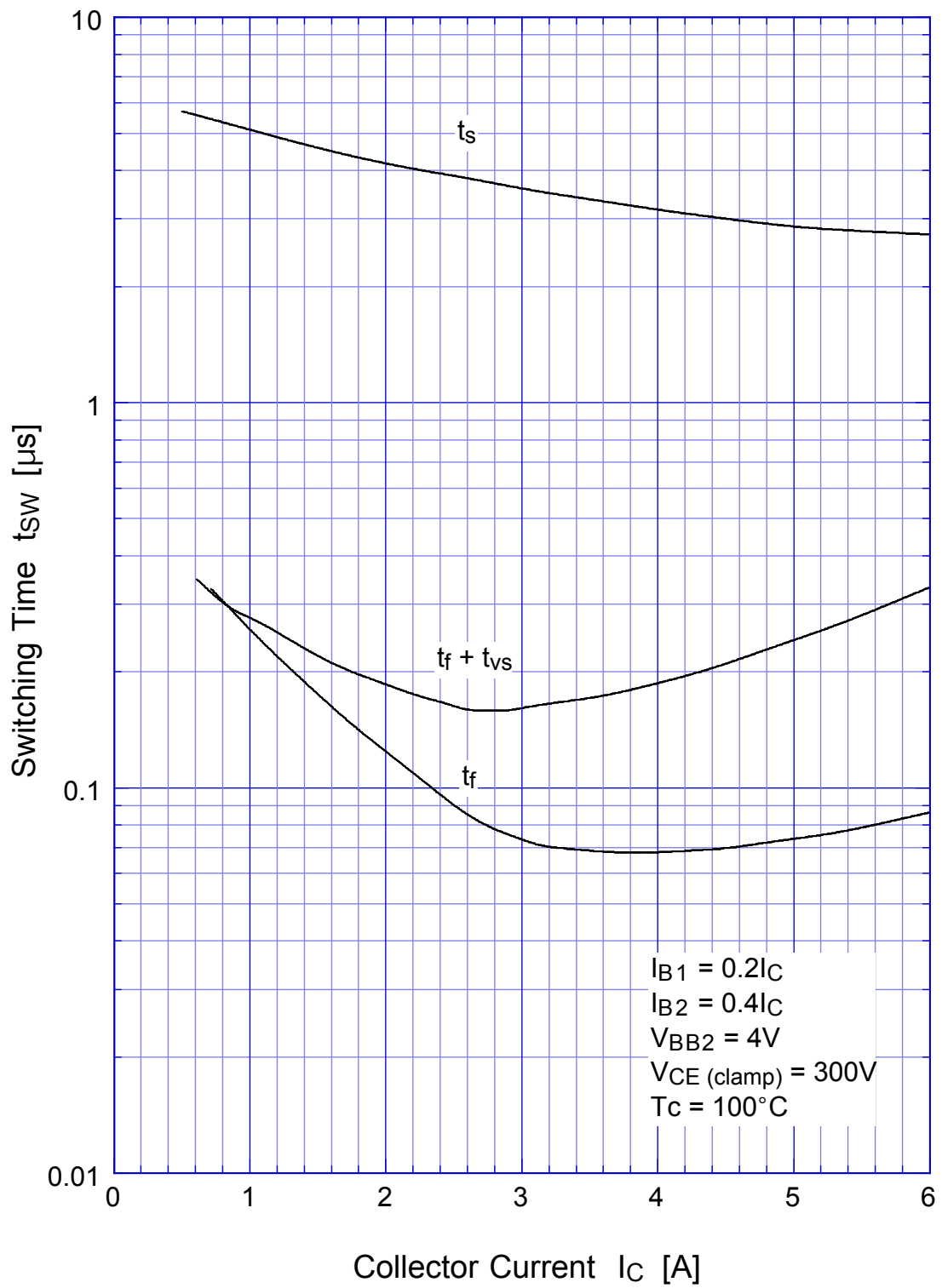
Switching Time - Tc



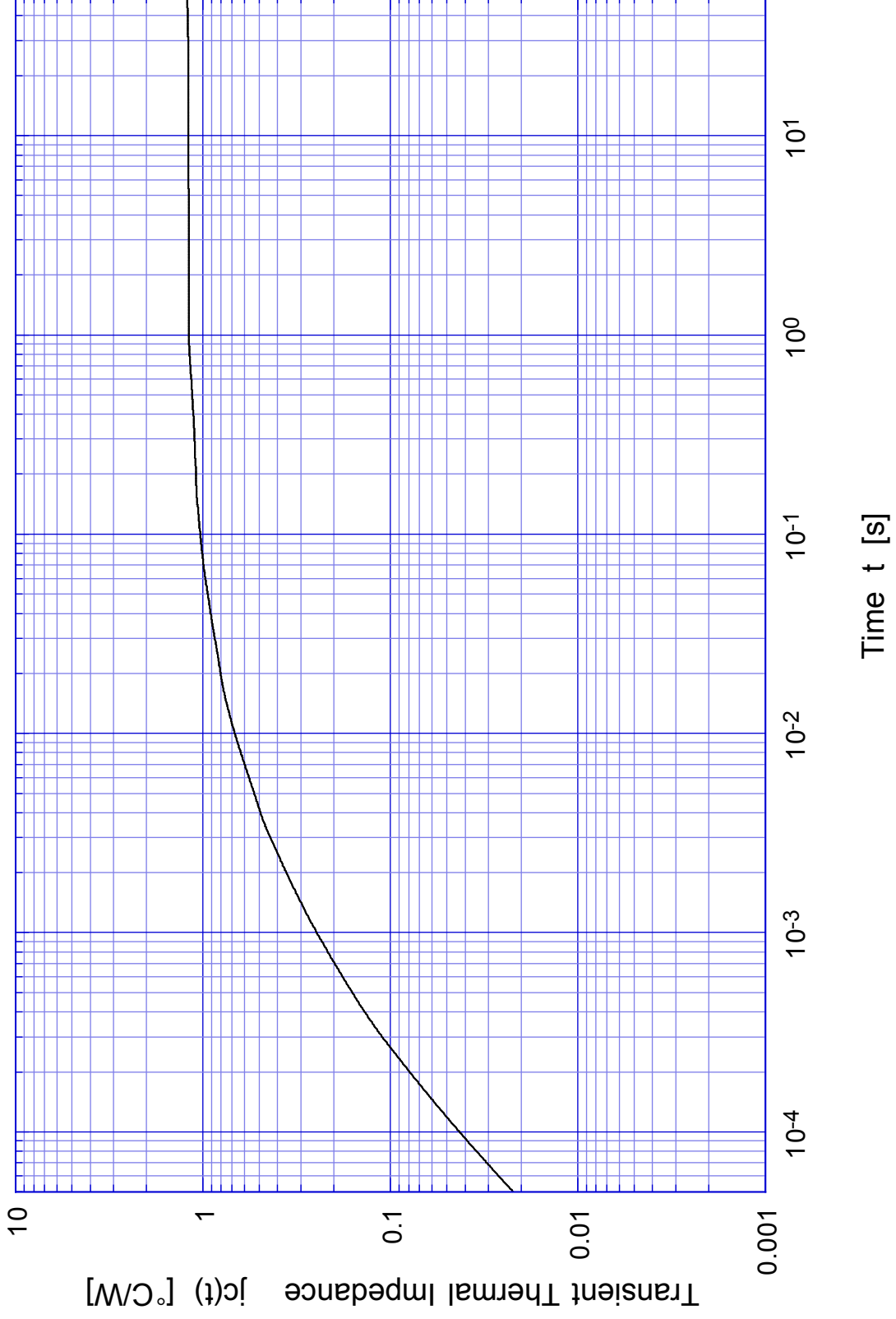
2SC4236 L-Load Switching Time - I_C



2SC4236 L-Load Switching Time - I_C (At High Temperature)

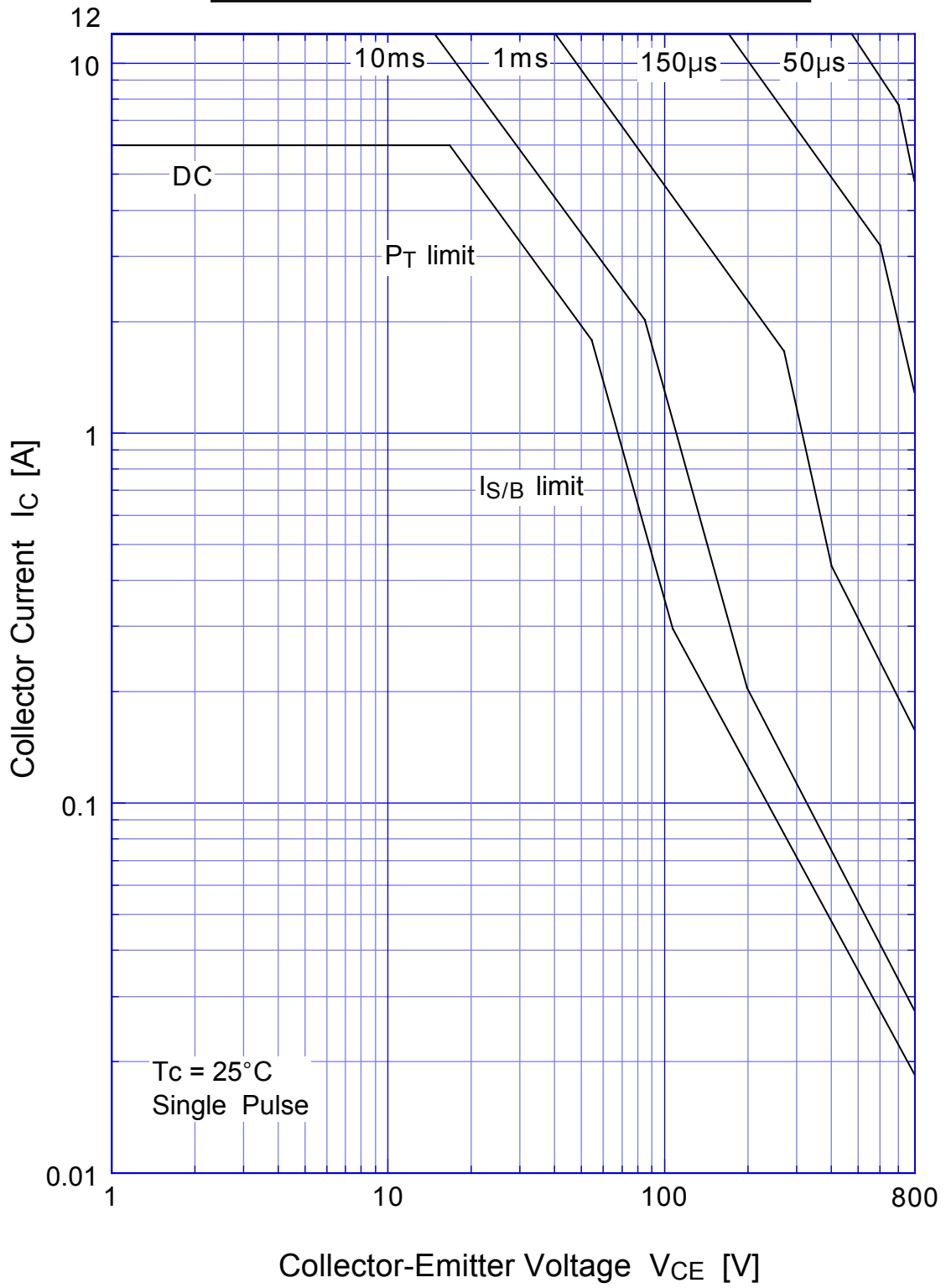


2SC4236 Transient Thermal Impedance



2SC4236

Forward Bias SOA



2SC4236 Collector Current Derating



2SC4236

Reverse Bias SOA

